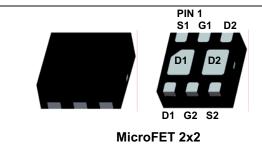
FAIRCHILD

# FDMA1028NZ Dual N-Channel PowerTrench<sup>®</sup> MOSFET

# **General Description**

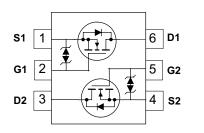
This device is designed specifically as a single package solution for dual switching requirements in cellular handset and other ultra-portable applications. It features two independent N-Channel MOSFETs with low on-state resistance for minimum conduction losses. The MicroFET 2x2 package offers exceptional thermal performance for its physical size and is well suited to linear mode applications.



# Features

■ 3.7 A, 20V.  $R_{DS(ON)} = 68 \text{ m}\Omega @ V_{GS} = 4.5V$  $R_{DS(ON)} = 86 \text{ m}\Omega @ V_{GS} = 2.5V$ 

- Low profile 0.8 mm maximum in the new package MicroFET 2x2 mm
- HBM ESD protection level > 2kV (Note 3)
- RoHS Compliant
- Free from halogenated compounds and antimony oxides



# Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

| Symbol          | Parameter                               |           | Ratings     | Units |
|-----------------|---|-----------|-------------|-------|
| V <sub>DS</sub> | Drain-Source Voltage                    |           | 20          | V     |
| V <sub>GS</sub> | Gate-Source Voltage                     |           | ±12         | V     |
| 1               | Drain Current – Continuous              | (Note 1a) | 3.7         | A     |
| I <sub>D</sub>  | – Pulsed                                |           | 6           |       |
| PD              | Power Dissipation for Single Operation  | (Note 1a) | 1.4         | W     |
|                 |   | (Note 1b) | 0.7         |       |
| TJ, TSTG        | Operating and Storage Junction Temperat | ure Range | -55 to +150 | °C    |

| $R_{	ext{	heta}JA}$ | Thermal Resistance, Junction-to-Ambient | (Note 1a) | 86 (Single Operation)  |      |
|---------------------|---|-----------|------------------------|------|
| $R_{	ext{	heta}JA}$ | Thermal Resistance, Junction-to-Ambient | (Note 1b) | 173 (Single Operation) | °C/W |
| $R_{	ext{	heta}JA}$ | Thermal Resistance, Junction-to-Ambient | (Note 1c) | 69 (Dual Operation)    | 0,00 |
| $R_{	heta JA}$      | Thermal Resistance, Junction-to-Ambient | (Note 1d) | 151 (Dual Operation)   |      |

# Package Marking and Ordering Information

| Device Marking | Device     | Reel Size | Tape width | Quantity |
|----------------|------------|-----------|------------|----------|
| 028            | FDMA1028NZ | 7"        | 7" 8mm     |          |

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| Symbol                                      | Parameter   | Test Conditions  | Min | Тур | Max | Units |
|---|---|--|-----|-----|-----|-------|
| Off Char                                    | acteristics                                       |  | •   |     |     |       |
| BV <sub>DSS</sub>                           | Drain-Source Breakdown Voltage                    | $V_{GS} = 0 V$ , $I_D = 250 \mu A$                                     | 20  |     |     | V     |
| <u>ΔBV<sub>DSS</sub></u><br>ΔT <sub>J</sub> | Breakdown Voltage Temperature<br>Coefficient      | $I_D$ = 250 µA, Referenced to 25°C                                     |     | 15  |     | mV/°C |
| I <sub>DSS</sub>                            | Zero Gate Voltage Drain Current                   | $V_{DS} = 16 V$ , $V_{GS} = 0 V$                                       |     |     | 1   | μA    |
| I <sub>GSS</sub>                            | Gate–Body Leakage                                 | $V_{GS} = \pm 12 V$ , $V_{DS} = 0 V$                                   |     |     | ±10 | μA    |
|   | acteristics (Note 2)                              |  | 0.6 | 1.0 | 1.5 | V     |
| V <sub>GS(th)</sub>                         | Gate Threshold Voltage                            | $V_{DS} = V_{GS}, I_D = 250 \ \mu A$                                   | 0.6 | 1.0 | 1.5 |       |
| $\frac{\Delta V_{GS(th)}}{\Delta T_J}$      | Gate Threshold Voltage<br>Temperature Coefficient | $I_D$ = 250 µA, Referenced to 25°C                                     |     | -4  |     | mV/°C |
| R <sub>DS(on)</sub>                         | Static Drain–Source                               | $V_{GS} = 4.5 V$ , $I_D = 3.7 A$                                       |     | 37  | 68  | mΩ    |
|   | On–Resistance                                     | $V_{GS} = 2.5 V$ , $I_D = 3.3 A$                                       |     | 50  | 86  |       |
|   |   | V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 3.7 A, T <sub>J</sub> =125°C |     | 53  | 90  |       |
| <b>g</b> fs                                 | Forward Transconductance                          | $V_{DS} = 10 V$ , $I_{D} = 3.7 A$                                      |     | 16  |     | s     |
| Dynamic                                     | Characteristics                                   |  |     |     |     |       |
| Ciss  | Input Capacitance                                 | $V_{DS} = 10 V$ , $V_{GS} = 0 V$ ,                                     |     | 340 |     | pF    |
| Coss  | Output Capacitance                                | f = 1.0 MHz  |     | 80  |     | pF    |
| C <sub>rss</sub>                            | Reverse Transfer Capacitance                      | 1  |     | 60  |     | pF    |
| Rg  | Gate Resistance                                   |  |     |     | 25  | Ω     |

# Switching Characteristics (Note 2)

|                     | <b>J ·</b> · · · · · · · · · · · · · · · · · |                          |                         |     |    |    |
|---------------------|--|--------------------------|-------------------------|-----|----|----|
| t <sub>d(on)</sub>  | Turn–On Delay Time                           |                          | I <sub>D</sub> = 1 A,   | 8   | 16 | ns |
| t <sub>r</sub>      | Turn–On Rise Time                            | V <sub>GS</sub> = 4.5 V, | $R_{GEN} = 6 \Omega$    | 8   | 16 | ns |
| t <sub>d(off)</sub> | Turn–Off Delay Time                          |                          |                         | 14  | 26 | ns |
| t <sub>f</sub>      | Turn–Off Fall Time                           |                          |                         | 3   | 6  | ns |
| Qg                  | Total Gate Charge                            | V <sub>DS</sub> = 10 V,  | I <sub>D</sub> = 3.7 A, | 4   | 6  | nC |
| Q <sub>gs</sub>     | Gate-Source Charge                           | V <sub>GS</sub> = 4.5 V  |                         | 0.7 |    | nC |
| Q <sub>gd</sub>     | Gate-Drain Charge                            |                          |                         | 1.1 |    | nC |

FDMA1028NZ Dual N-Channel PowerTrench<sup>®</sup> MOSFET

FDMA1028NZ Rev B6

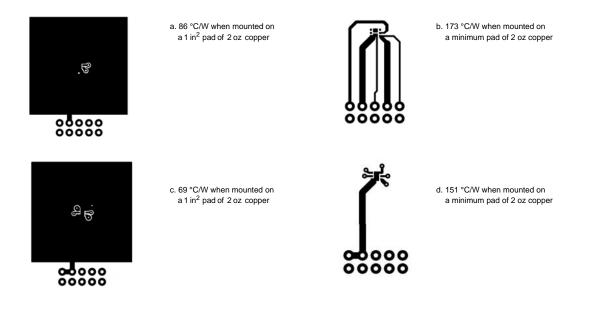
# FDMA1028NZ Dual N-Channel PowerTrench<sup>®</sup> MOSFET

# **Electrical Characteristics** $T_J = 25 \degree C$ unless otherwise noted

### Notes:

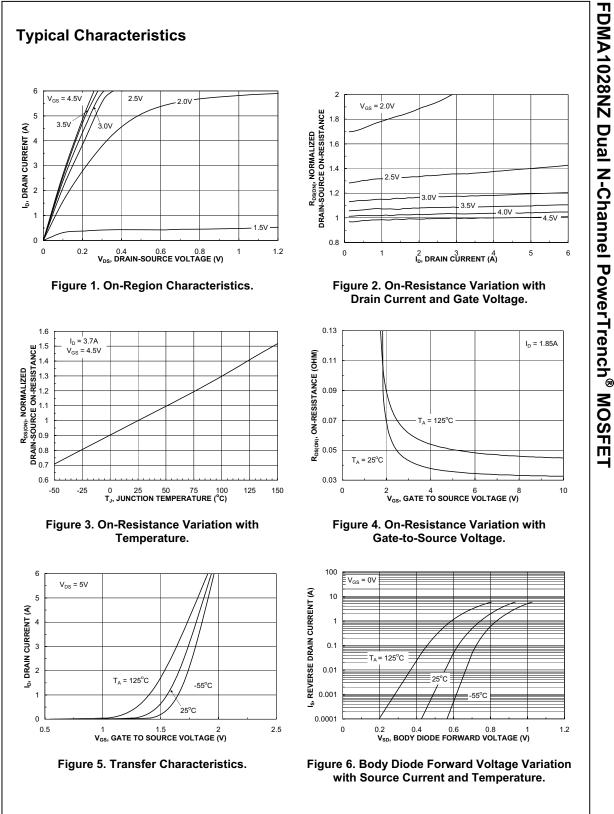
1. R<sub>8JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> oz. copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>8JA</sub> is guaranteed by design while R<sub>8JA</sub> is determined by the user's board design. (a)  $R_{0JA} = 86 \text{ °C/W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper, 1.5 " x 1.5 " x 0.062 " thick PCB. For single operation.

- (b) R<sub>0JA</sub> = 173 °C/W when mounted on a minimum pad of 2 oz copper. For single operation.
- (c)  $R_{0JA} = 69 \text{ °C/W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper, 1.5 " x 1.5 " x 0.062 " thick PCB. For dual operation.
- (d)  $R_{\theta JA}$  = 151  $^{o}\text{C/W}$  when mounted on a minimum pad of 2 oz copper. For dual operation.

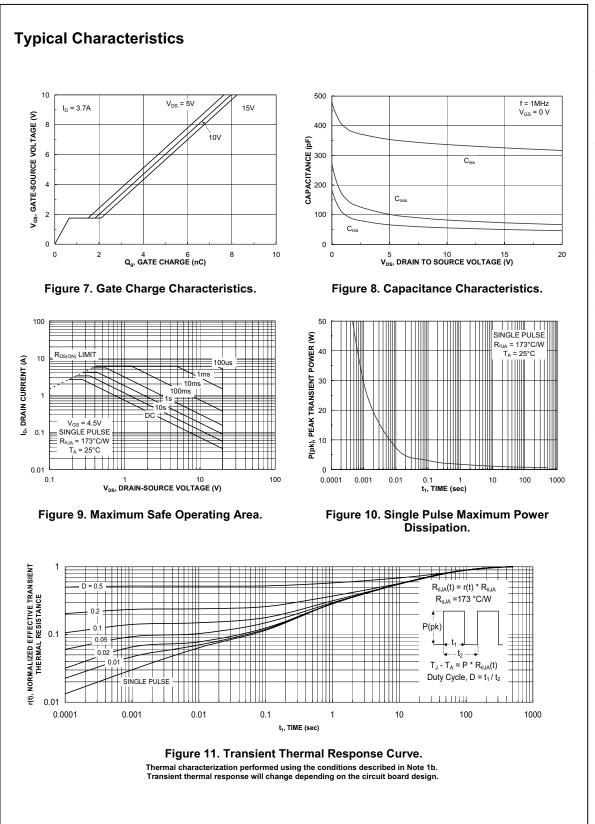


2. Pulse Test : Pulse Width < 300 us, Duty Cycle < 2.0%

3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

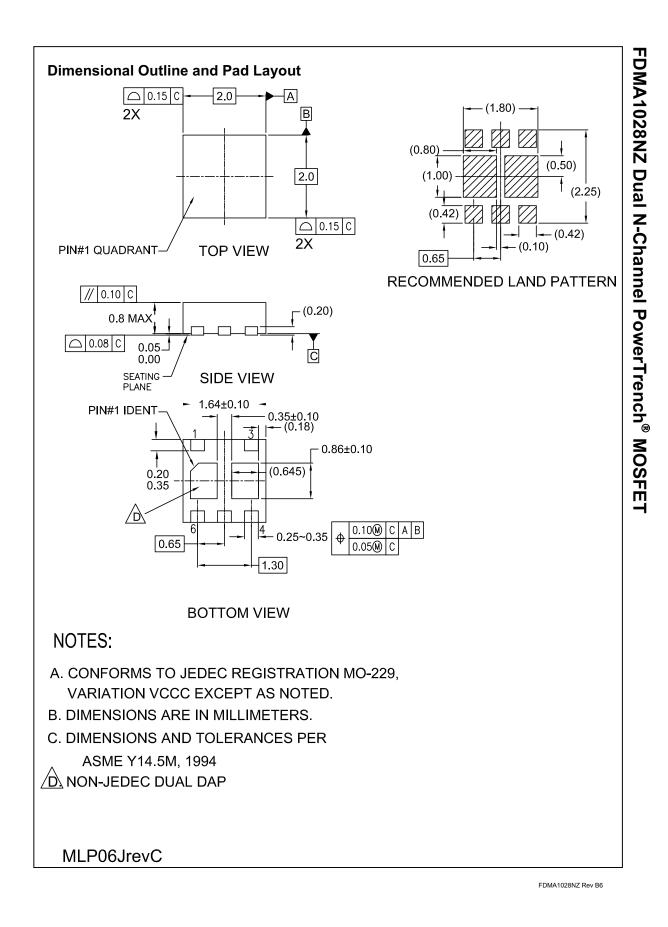


FDMA1028NZ Rev B6



FDMA1028NZ Dual N-Channel PowerTrench<sup>®</sup> MOSFET

FDMA1028NZ Rev B6





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